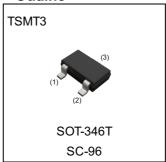


# General purpose amplification (-30V, -1A)

Parameter	Value
$V_{CEO}$	-30V
Ic	-1A

#### Outline

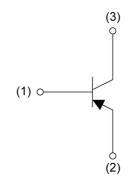


#### Features

- 1)A collector current is large.
- 2)Collector saturation voltage is low.

 $V_{CE(sat)} \le -350 \text{mV}$ at  $I_C = -500 \text{mA} / I_B = -25 \text{mA}$ 

#### •Inner circuit



- (1) Base
- (2) Emitter
- (3) Collector

#### Application

LOW FREQUENCY AMPLIFIER

#### Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SB1710	TSMT3	2928	TL	180	8	3000	EW

# ● Absolute maximum ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	$V_{CBO}$	-30	V
Collector-emitter voltage	V <sub>CEO</sub>	-30	V
Emitter-base voltage	V <sub>EBO</sub>	-6	V
Collector current	I <sub>C</sub>	-1	Α
Collector current	I <sub>CP</sub> *1	-2	Α
Dower dissination	P <sub>D</sub> *2	0.5	W
Power dissipation	P <sub>D</sub> *3	1.0	W
Junction temperature	Tj	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	လ

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Symbol	Conditions	Values			Linit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = -10μA	-30	-	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-30	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = -10μA	-6	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -30V	-	-	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -500mA, I <sub>B</sub> = -25mA	-	-150	-350	mV
DC current gain	h <sub>FE</sub>	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	f <sub>T</sub>	$V_{CE} = -2V, I_{E} = 100 \text{mA},$ f = 100MHz	-	320	-	MHz
Output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0A, f = 1MHz	-	7	-	pF

<sup>\*1</sup> Pw=1ms Single pulse

<sup>\*2</sup> Each Terminal Mounted on a Reference Land.

<sup>\*3</sup> Mounted on a ceramic board.( 25×25×0.8mm)

# ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

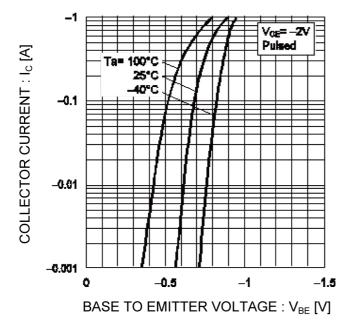
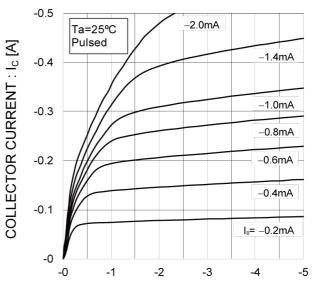


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]

Fig.3 DC Current Gain vs. Collector Current (I)

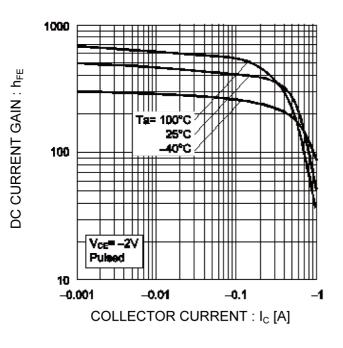
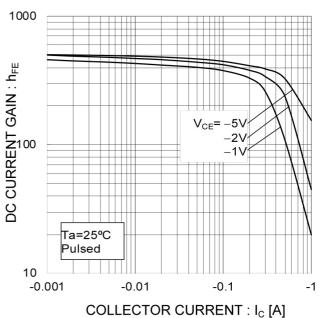


Fig.4 DC Current Gain vs. Collector Current (II)



# ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

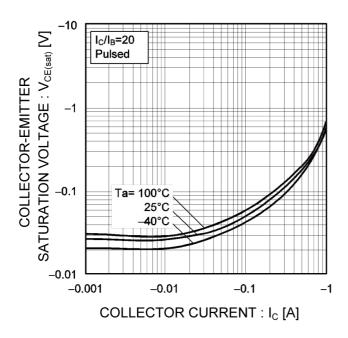


Fig.6 Collector-Emitter Saturation
Voltage vs. Collector Current (II)

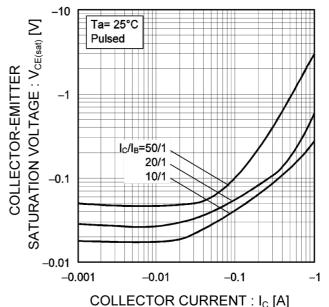


Fig.7 Base-Emitter Saturation Voltage vs.
Collector Current

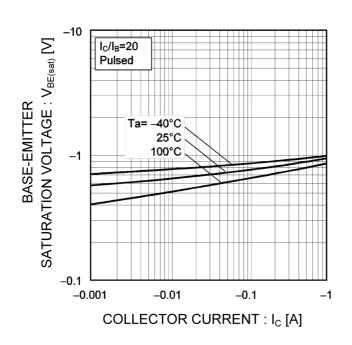
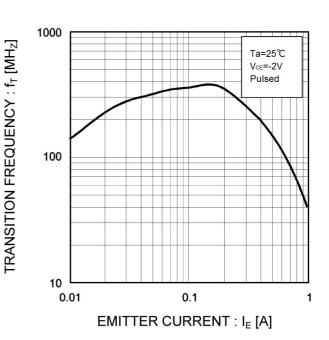


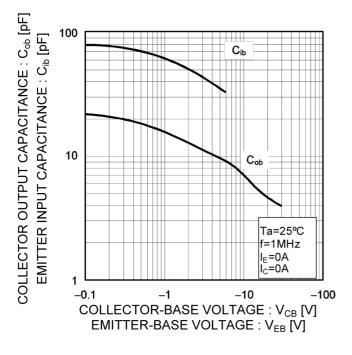
Fig.8 Gain Bandwidth Product vs. Emitter Current

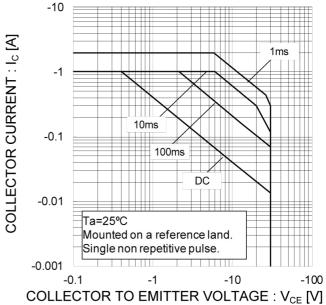


# ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.9 Emitter Input Capacitance vs.
Emitter-Base Voltage
Collector Output Capacitance vs.
Collector-Base Voltage

Fig.10 Safe Operating Area

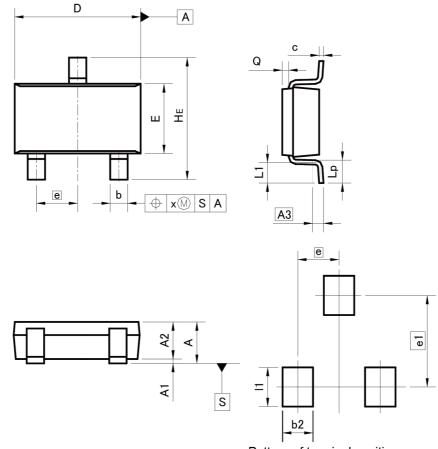




ROHM

#### Dimensions

TSMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	DIM MILIMETERS			HES	
DIM	MIN		MAX MIN		
Α	-	1.00	ı	0.039	
A1	0.00	0.10	0.000	0.004	
A2	0.75	0.95	0.030	0.037	
A3	0.:	25	0.010		
b	0.35	0.50	0.014	0.020	
С	0.10	0.26	0.004	0.010	
D	2.80	3.00	0.110	0.118	
E	1.50	1.80 0.059		0.071	
е	0.9	95	0.0	37	
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.05	0.25	0.002	0.010	
х	_	0.20	_	0.008	

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b2		0.70	-	0.028	
e1	2.10		0.0	83	
l1	_	0.90	ı	0.035	

Dimension in mm/inches



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